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Details

Product Status	Active
Core Processor	H8/300L
Core Size	8-Bit
Speed	8MHz
Connectivity	SCI
Peripherals	LCD, PWM, WDT
Number of I/O	55
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 8x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	80-BQFP
Supplier Device Package	80-QFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/df38324hwv

1.3 Pin Arrangement and Functions

1.3.1 Pin Arrangement

The pin arrangements of the H8/3827R Group, H8/3827S Group, H8/38327 Group, and H8/38427 Group are shown in figures 1.2 and 1.3 (figure 1.3 only applies to the H8/3827R Group). The bonding pad location diagram of the H8/3827R Group (mask ROM version) is shown in figure 1.4, and the bonding pad coordinates are given in table 1.2. The bonding pad location diagram of the H8/3827S Group (mask ROM version) is shown in figure 1.5, and the bonding pad coordinates are given in table 1.3. The bonding pad location diagram of the HCD64F38327 and HCD64F38427 is shown in figure 1.6, and the bonding pad coordinates are given in table 1.4. The bonding pad location diagram of the H8/38327 Group (mask ROM version) and H8/38427 Group (mask ROM version) is shown in figure 1.7, and the bonding pad coordinates are given in table 1.5.

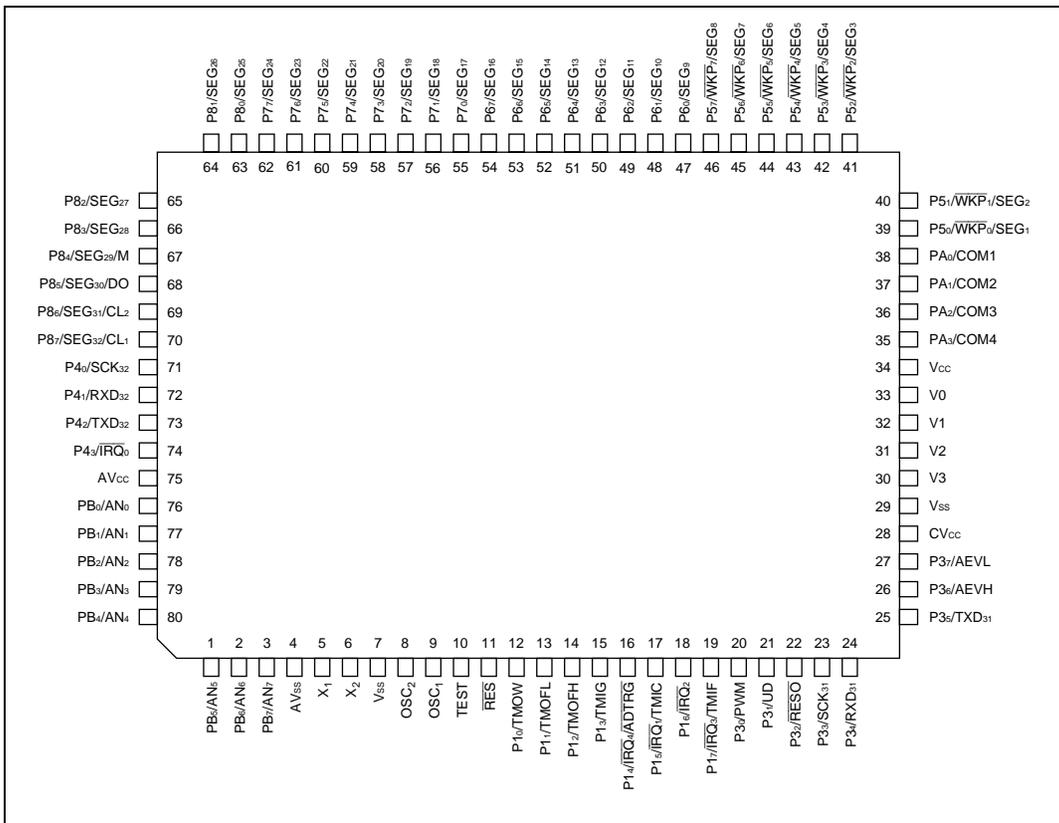


Figure 1.3 Pin Arrangement (FP-80B: Top View)

2.3.1 Data Formats in General Registers

Data of all the sizes above can be stored in general registers as shown in figure 2.3.

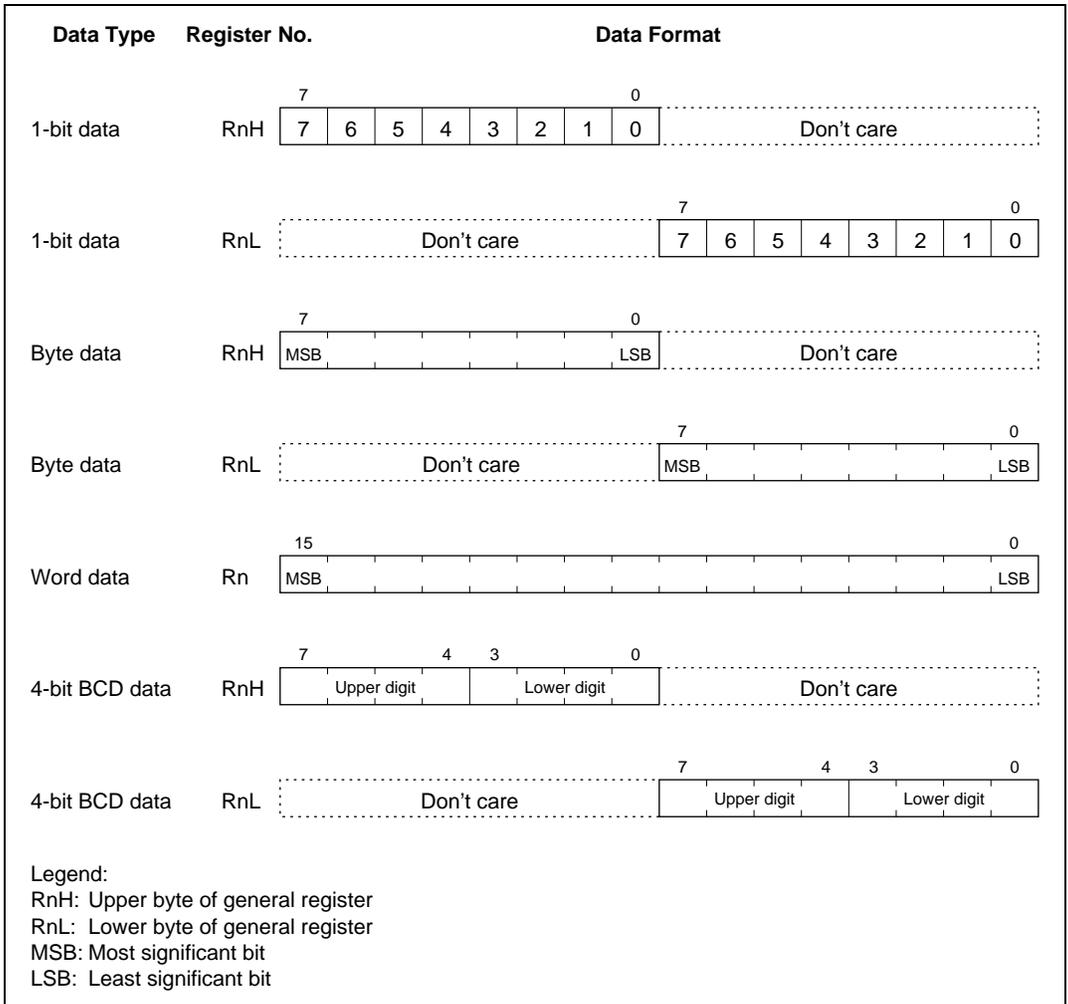


Figure 2.3 Register Data Formats

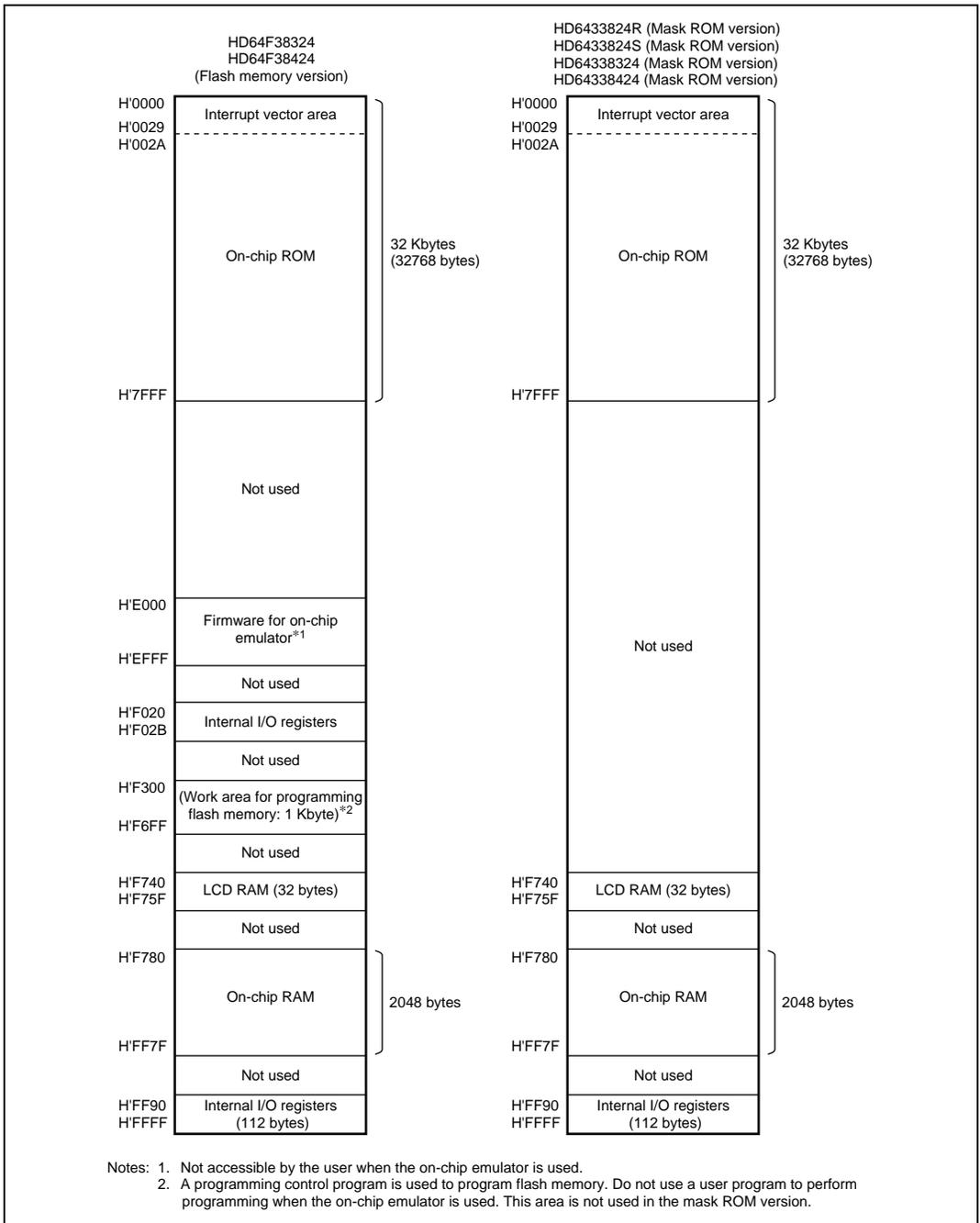


Figure 2.16 (3) H8/3824R, H8/3824S, H8/38324, and H8/38424 Memory Map

Bits 1 and 0: Active (medium-speed) mode clock select (MA1, MA0)

Bits 1 and 0 choose $\phi_{osc}/128$, $\phi_{osc}/64$, $\phi_{osc}/32$, or $\phi_{osc}/16$ as the operating clock in active (medium-speed) mode and sleep (medium-speed) mode. MA1 and MA0 should be written in active (high-speed) mode or subactive mode.

Bit 1 MA1	Bit 0 MA0	Description
0	0	$\phi_{osc}/16$
0	1	$\phi_{osc}/32$
1	0	$\phi_{osc}/64$
1	1	$\phi_{osc}/128$ (initial value)

2. System Control Register 2 (SYSCR2)

Bit	7	6	5	4	3	2	1	0
	—	—	—	NESEL	DTON	MSON	SA1	SA0
Initial value	1	1	1	1	0	0	0	0
Read/Write	—	—	—	R/W	R/W	R/W	R/W	R/W

SYSCR2 is an 8-bit read/write register for power-down mode control.

Bits 7 to 5: Reserved bits

These bits are reserved; they are always read as 1, and cannot be modified.

Bit 4: Noise elimination sampling frequency select (NESEL)

This bit selects the frequency at which the watch clock signal (ϕ_w) generated by the subclock pulse generator is sampled, in relation to the oscillator clock (ϕ_{osc}) generated by the system clock pulse generator. When $\phi_{osc} = 2$ to 16 MHz, clear NESEL to 0.

Bit 4

NESEL	Description
0	Sampling rate is $\phi_{osc}/16$
1	Sampling rate is $\phi_{osc}/4$ (initial value)

2. Time for Direct Transition from Active (Medium-Speed) Mode to Active (High-Speed) Mode

A direct transition from active (medium-speed) mode to active (high-speed) mode is performed by executing a SLEEP instruction in active (medium-speed) mode while bits SSBY and LSON are both cleared to 0 in SYSCR1, and bit MSON is cleared to 0 and bit DTON is set to 1 in SYSCR2. The time from execution of the SLEEP instruction to the end of interrupt exception handling (the direct transition time) is given by equation (2) below.

$$\text{Direct transition time} = \{ (\text{Number of SLEEP instruction execution states}) + (\text{number of internal processing states}) \} \times (\text{tcyc before transition}) + (\text{number of interrupt exception handling execution states}) \times (\text{tcyc after transition}) \dots\dots\dots (2)$$

Example: Direct transition time = $(2 + 1) \times 16\text{tosc} + 14 \times 2\text{tosc} = 76\text{tosc}$ (when $\phi/8$ is selected as the CPU operating clock)

Notation:

tosc: OSC clock cycle time

tcyc: System clock (ϕ) cycle time

3. Time for Direct Transition from Subactive Mode to Active (High-Speed) Mode

A direct transition from subactive mode to active (high-speed) mode is performed by executing a SLEEP instruction in subactive mode while bit SSBY is set to 1 and bit LSON is cleared to 0 in SYSCR1, bit MSON is cleared to 0 and bit DTON is set to 1 in SYSCR2, and bit TMA3 is set to 1 in TMA. The time from execution of the SLEEP instruction to the end of interrupt exception handling (the direct transition time) is given by equation (3) below.

$$\text{Direct transition time} = \{ (\text{Number of SLEEP instruction execution states}) + (\text{number of internal processing states}) \} \times (\text{tsubcyc before transition}) + \{ (\text{wait time set in STS2 to STS0}) + (\text{number of interrupt exception handling execution states}) \} \times (\text{tcyc after transition}) \dots\dots\dots (3)$$

Example: Direct transition time = $(2 + 1) \times 8\text{tw} + (8192 + 14) \times 2\text{tosc} = 24\text{tw} + 16412\text{tosc}$ (when $\phi_w/8$ is selected as the CPU operating clock, and wait time = 8192 states)

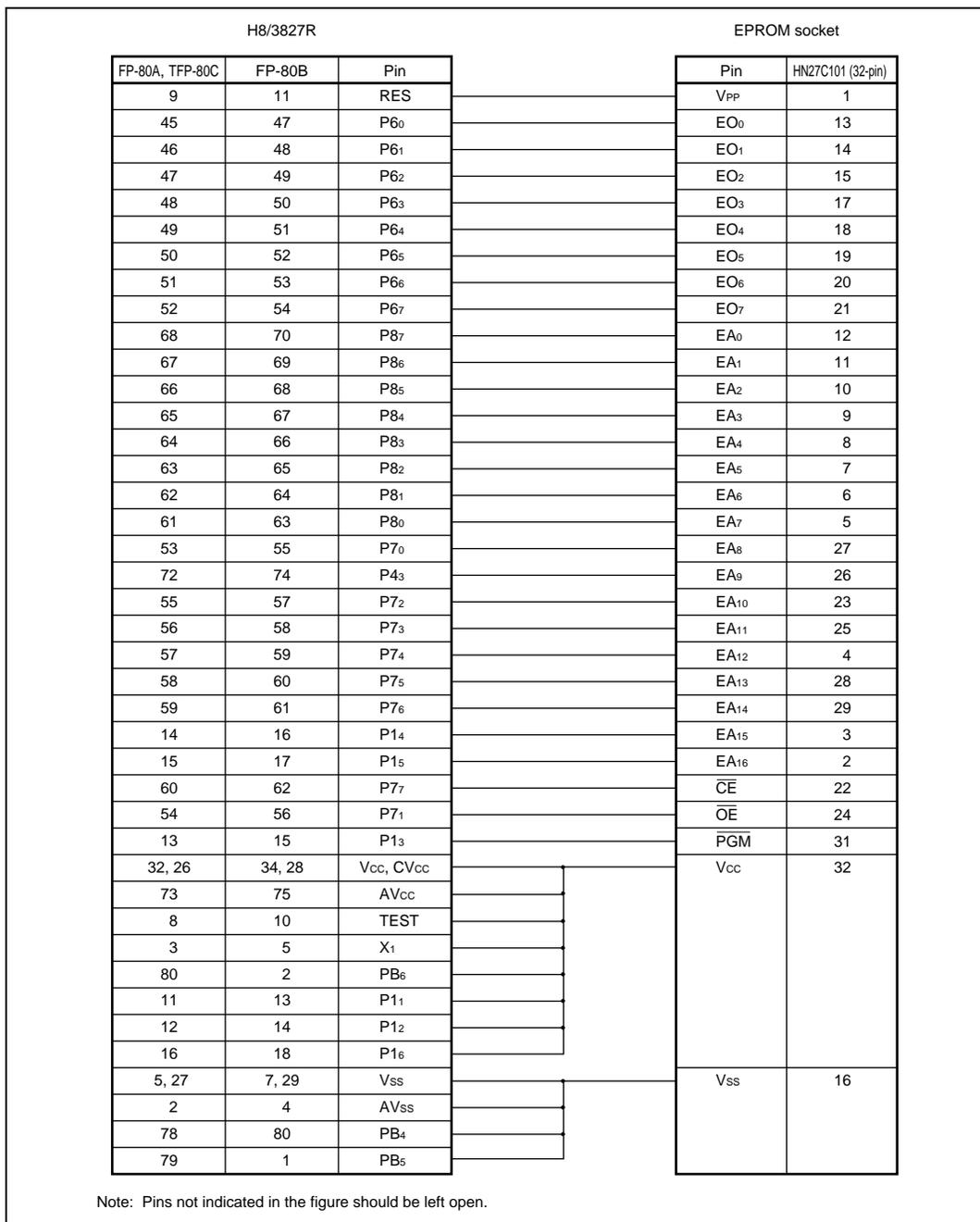
Notation:

tosc: OSC clock cycle time

tw: Watch clock cycle time

tcyc: System clock (ϕ) cycle time

tsubcyc: Subclock (ϕ_{SUB}) cycle time



Note: Pins not indicated in the figure should be left open.

Figure 6.2 Socket Adapter Pin Correspondence (with HN27C101)

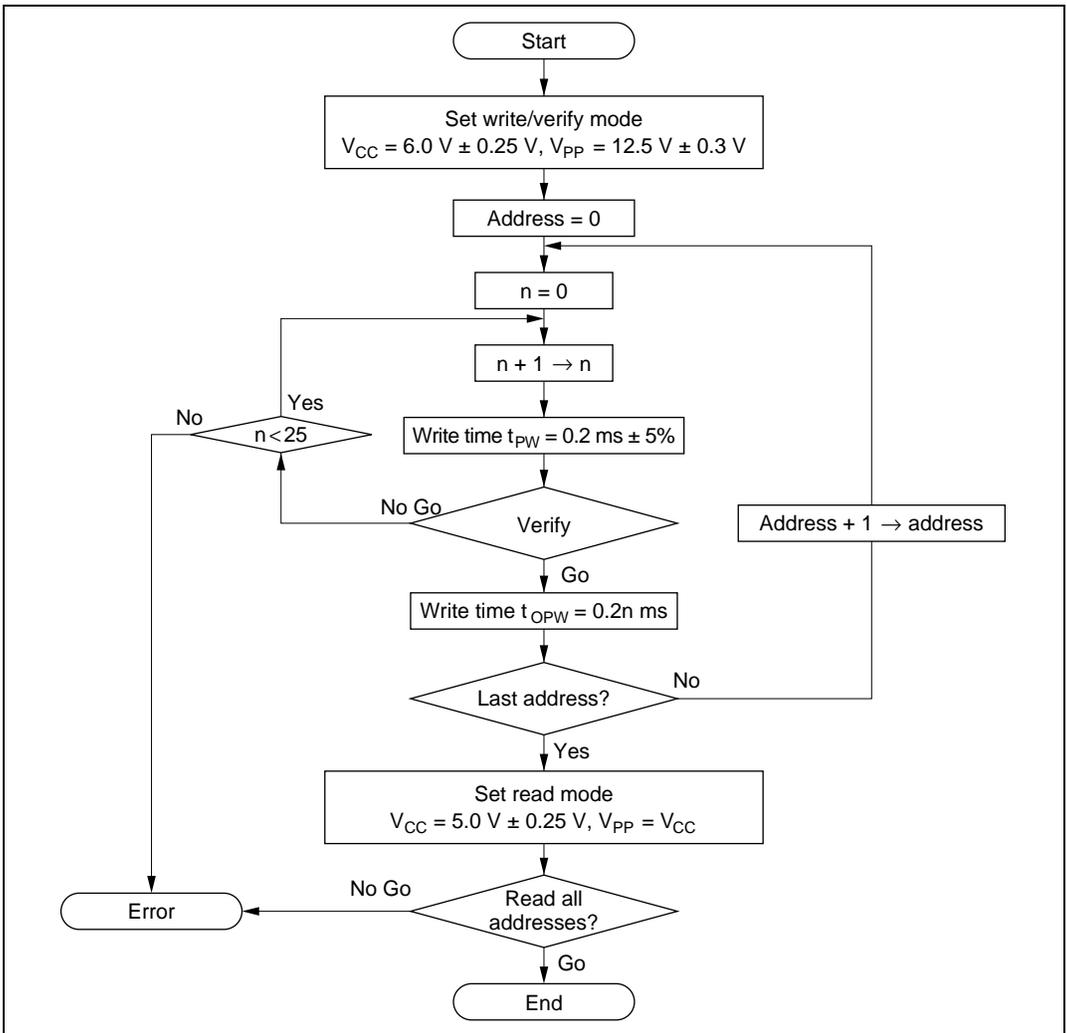


Figure 6.4 High-Speed, High-Reliability Programming Flow Chart

3. Port Pull-Up Control Register 3 (PUCR3)

Bit	7	6	5	4	3	2	1	0
	PUCR3 ₇	PUCR3 ₆	PUCR3 ₅	PUCR3 ₄	PUCR3 ₃	PUCR3 ₂	PUCR3 ₁	PUCR3 ₀
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W							

PUCR3 controls whether the MOS pull-up of each of the port 3 pins P3₇ to P3₀ is on or off. When a PCR3 bit is cleared to 0, setting the corresponding PUCR3 bit to 1 turns on the MOS pull-up for the corresponding pin, while clearing the bit to 0 turns off the MOS pull-up.

Upon reset, PUCR3 is initialized to H'00.

4. Port Mode Register 3 (PMR3)

Bit	7	6	5	4	3	2	1	0
	AEVL	AEVH	WDCKS	NCS	IRQ0	RESO*	UD	PWM
Initial value	0	0	0	0	0	1	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Note: * The RESO bit is not implemented in the H8/38327 Group and H8/38427 Group.

PMR3 is an 8-bit read/write register, controlling the selection of pin functions for port 3 pins.

Upon reset, PMR3 is initialized to H'04.

Bit 7: P3₇/AEVL pin function switch (AEVL)

This bit selects whether pin P3₇/AEVL is used as P3₇ or as AEVL.

Bit 7

AEVL	Description
0	Functions as P3 ₇ I/O pin (initial value)
1	Functions as AEVL input pin

2. Timer Counter C (TCC)

Bit	7	6	5	4	3	2	1	0
	TCC7	TCC6	TCC5	TCC4	TCC3	TCC2	TCC1	TCC0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R	R	R	R	R	R	R	R

TCC is an 8-bit read-only up-counter, which is incremented by internal clock or external event input. The clock source for input to this counter is selected by bits TMC2 to TMC0 in timer mode register C (TMC). TCC values can be read by the CPU at any time.

When TCC overflows from H'FF to H'00 or to the value set in TLC, or underflows from H'00 to H'FF or to the value set in TLC, the IRRTC bit in IRR2 is set to 1.

TCC is allocated to the same address as TLC.

Upon reset, TCC is initialized to H'00.

3. Timer Load Register C (TLC)

Bit	7	6	5	4	3	2	1	0
	TLC7	TLC6	TLC5	TLC4	TLC3	TLC2	TLC1	TLC0
Initial value	0	0	0	0	0	0	0	0
Read/Write	W	W	W	W	W	W	W	W

TLC is an 8-bit write-only register for setting the reload value of timer counter C (TCC).

When a reload value is set in TLC, the same value is loaded into timer counter C as well, and TCC starts counting up from that value. When TCC overflows or underflows during operation in auto-reload mode, the TLC value is loaded into TCC. Accordingly, overflow/underflow periods can be set within the range of 1 to 256 input clocks.

The same address is allocated to TLC as to TCC.

Upon reset, TLC is initialized to H'00.

2. Block Diagram

Figure 9.3 shows a block diagram of timer F.

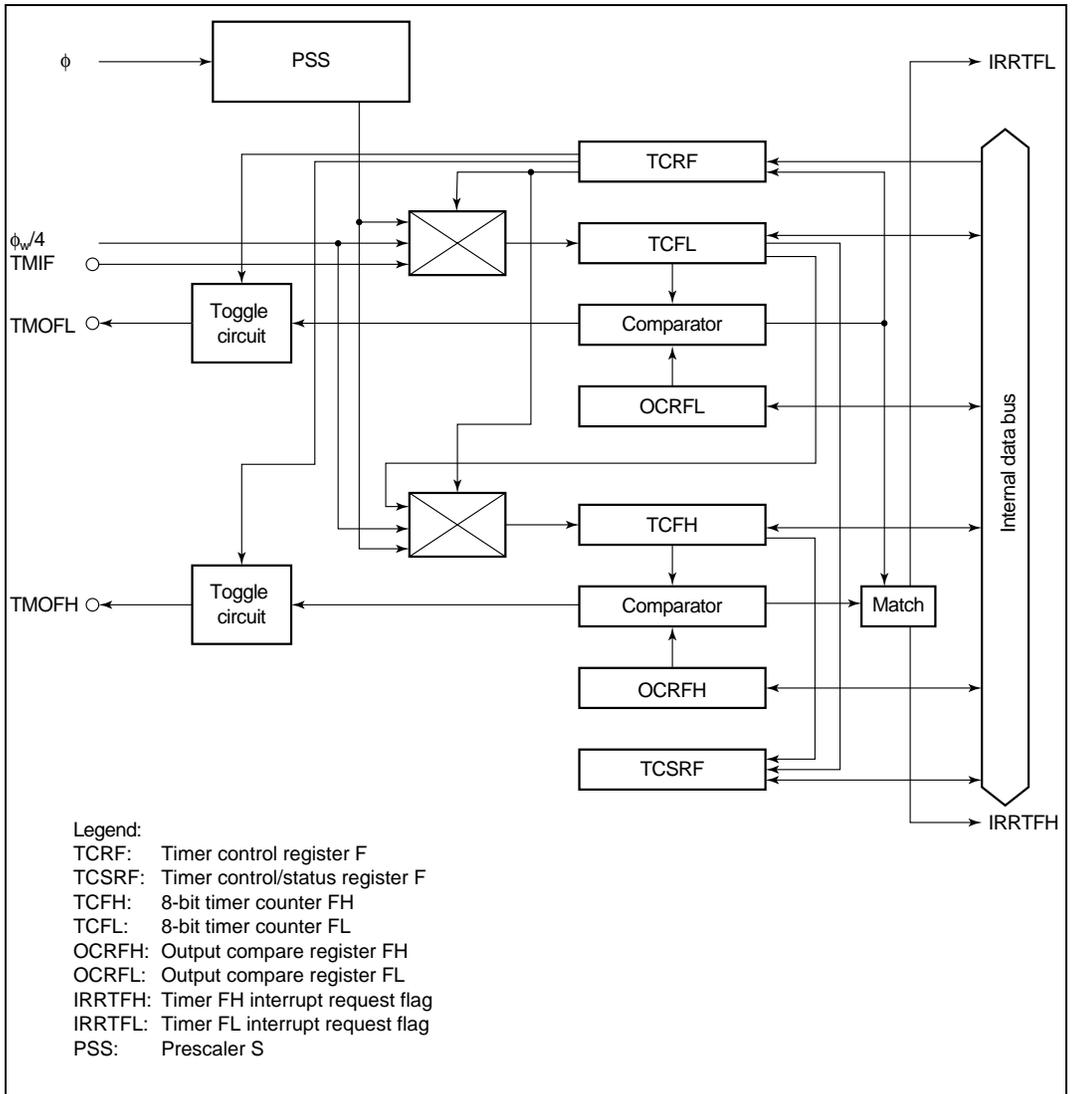


Figure 9.3 Block Diagram of Timer F

Bit 7: Counter overflow flag H (OVH)

Bit 7 is a status flag indicating that ECH has overflowed from H'FF to H'00. This flag is set when ECH overflows. It is cleared by software but cannot be set by software. OVH is cleared by reading it when set to 1, then writing 0.

When ECH and ECL are used as a 16-bit event counter with CH2 cleared to 0, OVH functions as a status flag indicating that the 16-bit event counter has overflowed from H'FFFF to H'0000.

Bit 7

OVH	Description	
0	ECH has not overflowed Clearing condition: After reading OVH = 1, cleared by writing 0 to OVH	(initial value)
1	ECH has overflowed Setting condition: Set when ECH overflows from H'FF to H'00	

Bit 6: Counter overflow flag L (OVL)

Bit 6 is a status flag indicating that ECL has overflowed from H'FF to H'00. This flag is set when ECL overflows. It is cleared by software but cannot be set by software. OVL is cleared by reading it when set to 1, then writing 0.

Bit 6

OVL	Description	
0	ECL has not overflowed Clearing condition: After reading OVL = 1, cleared by writing 0 to OVL	(initial value)
1	ECL has overflowed Setting condition: Set when ECL overflows from H'FF to H'00 while CH2 is set to 1	

Bit 5: Reserved bit

Bit 5 is reserved; it can be read and written, and is initialized to 0 upon reset.

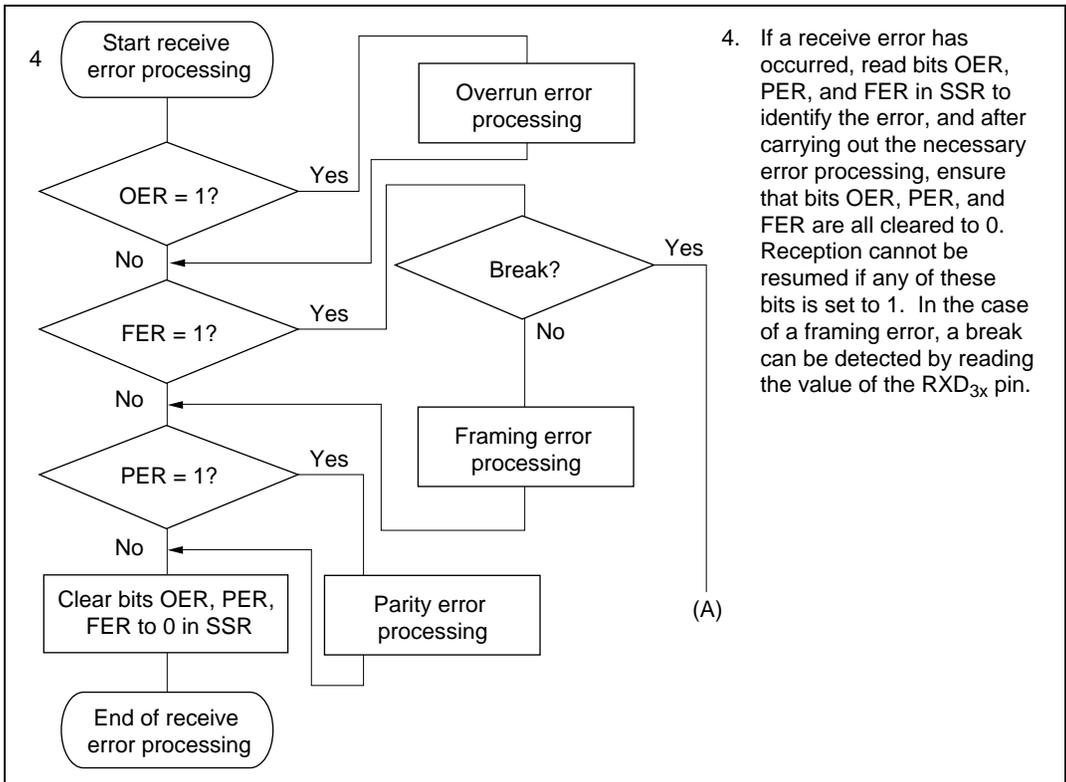


Figure 10.8 Example of Data Reception Flowchart (Asynchronous Mode) (cont)

Bit 4: Display data control (DISP)

Bit 4 specifies whether the LCD RAM contents are displayed or blank data is displayed regardless of the LCD RAM contents.

**Bit 4
DISP**

	Description	
0	Blank data is displayed	(initial value)
1	LCD RAM data is display	

Bits 3 to 0: Frame frequency select 3 to 0 (CKS3 to CKS0)

Bits 3 to 0 select the operating clock and the frame frequency. In subactive mode, watch mode, and subsleep mode, the system clock (ϕ) is halted, and therefore display operations are not performed if one of the clocks from $\phi/2$ to $\phi/256$ is selected. If LCD display is required in these modes, ϕ_w , $\phi_w/2$, or $\phi_w/4$ must be selected as the operating clock.

Bit 3 CKS3	Bit 2 CKS2	Bit 1 CKS1	Bit 0 CKS0	Operating Clock	Frame Frequency* ²	
					$\phi = 2 \text{ MHz}$	$\phi = 250 \text{ kHz}$ * ¹
0	*	0	0	ϕ_w	128 Hz* ³ (initial value)	
0	*	0	1	$\phi_w/2$	64 Hz* ³	
0	*	1	*	$\phi_w/4$	32 Hz* ³	
1	0	0	0	$\phi/2$	—	244 Hz
1	0	0	1	$\phi/4$	977 Hz	122 Hz
1	0	1	0	$\phi/8$	488 Hz	61 Hz
1	0	1	1	$\phi/16$	244 Hz	30.5 Hz
1	1	0	0	$\phi/32$	122 Hz	—
1	1	0	1	$\phi/64$	61 Hz	—
1	1	1	0	$\phi/128$	30.5 Hz	—
1	1	1	1	$\phi/256$	—	—

*: Don't care

- Notes: 1. This is the frame frequency in active (medium-speed, $\phi_{osc}/16$) mode when $\phi = 2 \text{ MHz}$.
 2. When 1/3 duty is selected, the frame frequency is 4/3 times the value shown.
 3. This is the frame frequency when $\phi_w = 32.768 \text{ kHz}$.

13.3.2 Relationship between LCD RAM and Display

The relationship between the LCD RAM and the display segments differs according to the duty cycle. LCD RAM maps for the different duty cycles when segment external expansion is not used are shown in figures 13.5 to 13.8, and LCD RAM maps when segment external expansion is used in figures 13.9 to 13.12.

After setting the registers required for display, data is written to the part corresponding to the duty cycle using the same kind of instruction as for ordinary RAM, and display is started automatically when turned on. Word- or byte-access instructions can be used for RAM setting.

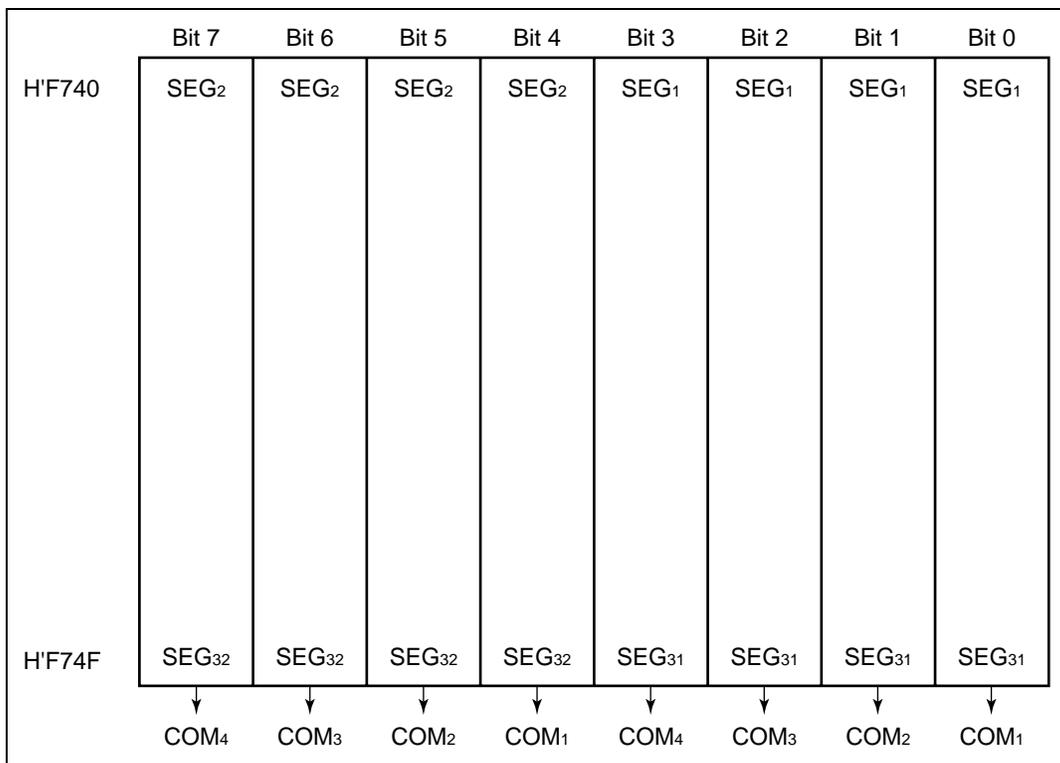


Figure 13.5 LCD RAM Map when Not Using Segment External Expansion (1/4 Duty)

15.2.5 LCD Characteristics

Table 15.6 shows the LCD characteristics.

Table 15.6 LCD Characteristics

$V_{CC} = 1.8\text{ V to }5.5\text{ V}$, $AV_{CC} = 1.8\text{ V to }5.5\text{ V}$, $V_{SS} = AV_{SS} = 0.0\text{ V}$, $T_a = -20^\circ\text{C to }+75^\circ\text{C}^{*3}$
(including subactive mode) unless otherwise specified.

Item	Symbol	Applicable Pins	Test Conditions	Values			Unit	Notes
				Min	Typ	Max		
Segment driver drop voltage	V_{DS}	SEG ₁ to SEG ₃₂	$I_D = 2\ \mu\text{A}$ $V_1 = 2.7\text{ to }5.5\text{ V}$	—	—	0.6	V	*1
Common driver drop voltage	V_{DC}	COM ₁ to COM ₄	$I_D = 2\ \mu\text{A}$ $V_1 = 2.7\text{ to }5.5\text{ V}$	—	—	0.3	V	*1
LCD power supply split-resistance	R_{LCD}		Between V_1 and V_{SS}	0.5	3.0	9.0	MΩ	
Liquid crystal display voltage	V_{LCD}	V_1		2.2	—	5.5	V	*2

- Notes: 1. The voltage drop from power supply pins V_1 , V_2 , V_3 , and V_{SS} to each segment pin or common pin.
2. When the liquid crystal display voltage is supplied from an external power source, ensure that the following relationship is maintained: $V_1 \geq V_2 \geq V_3 \geq V_{SS}$.
3. The guaranteed temperature as an electrical characteristic for Die products is 75°C.

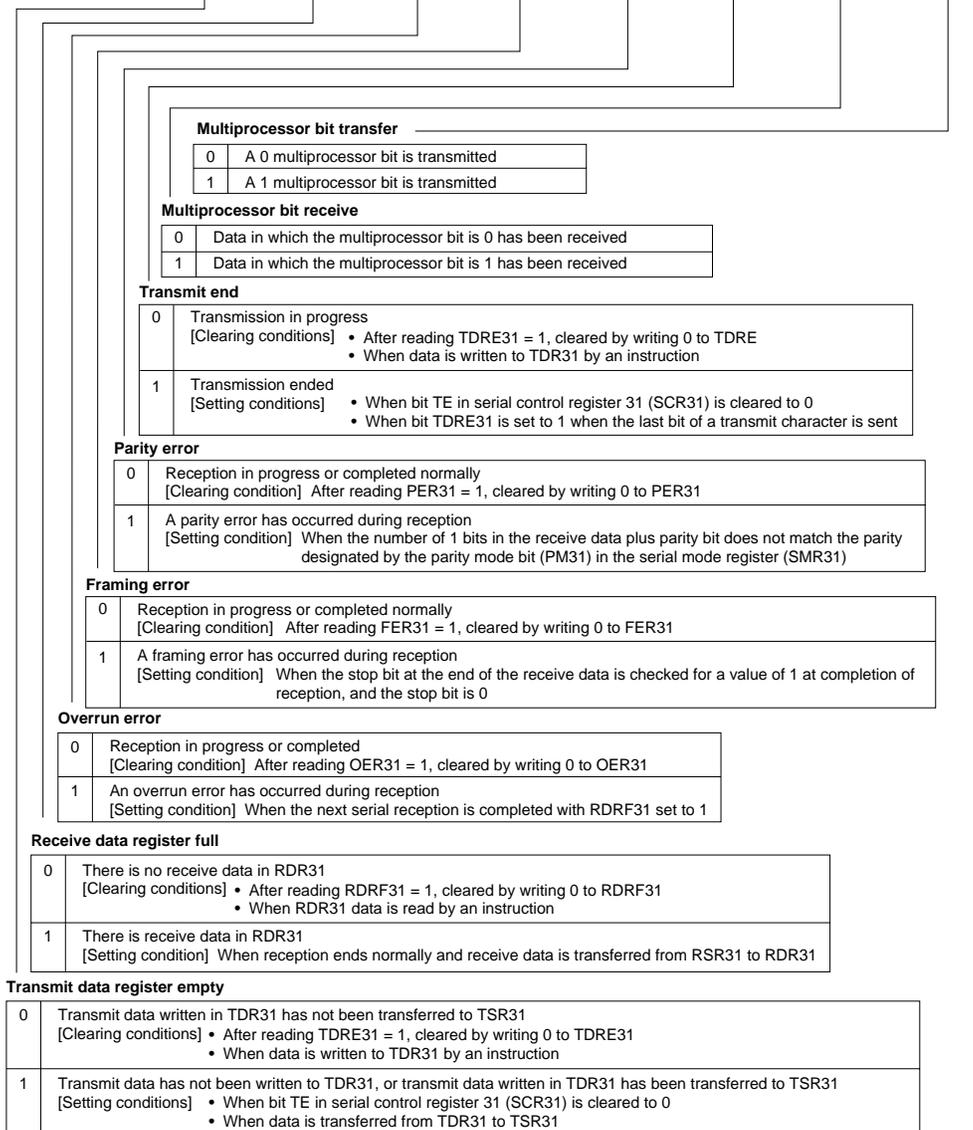
Item	Symbol	Applicable Pins	Values			Unit	Test Condition	Notes	
			Min	Typ	Max				
Output low voltage	V_{OL}	P1 ₀ to P1 ₇ , P4 ₀ to P4 ₂	—	—	0.6	V	$V_{CC} = 4.0 \text{ V to } 5.5 \text{ V}$ $I_{OL} = 1.6 \text{ mA}$		
			—	—	0.5		$I_{OL} = 0.4 \text{ mA}$		
		P5 ₀ to P5 ₇ , P6 ₀ to P6 ₇ , P7 ₀ to P7 ₇ , P8 ₀ to P8 ₇ , PA ₀ to PA ₃	—	—	0.5		$I_{OL} = 0.4 \text{ mA}$		
			P3 ₀ to P3 ₇	—	—	1.5			$V_{CC} = 4.0 \text{ V to } 5.5 \text{ V}$ $I_{OL} = 10 \text{ mA}$
				—	—	0.6			$V_{CC} = 4.0 \text{ V to } 5.5 \text{ V}$ $I_{OL} = 1.6 \text{ mA}$
—	—	0.5		$I_{OL} = 0.4 \text{ mA}$					
Input/output leakage current	$ I_{IL} $	\overline{RES} , P4 ₃	—	—	20.0	μA	$V_{IN} = 0.5 \text{ V to}$ $V_{CC} - 0.5 \text{ V}$	*2	
			—	—	1.0			*1	
		OSC ₁ , X ₁ , P1 ₀ to P1 ₇ , P3 ₀ to P3 ₇ , P4 ₀ to P4 ₂ , P5 ₀ to P5 ₇ , P6 ₀ to P6 ₇ , P7 ₀ to P7 ₇ , P8 ₀ to P8 ₇ , PA ₀ to PA ₃	—	—	1.0	μA	$V_{IN} = 0.5 \text{ V to}$ $V_{CC} - 0.5 \text{ V}$		
		PB ₀ to PB ₇	—	—	1.0		$V_{IN} = 0.5 \text{ V to}$ $AV_{CC} - 0.5 \text{ V}$		
Pull-up MOS current	$-I_p$	P1 ₀ to P1 ₇ , P3 ₀ to P3 ₇ , P5 ₀ to P5 ₇ , P6 ₀ to P6 ₇	50.0	—	300.0	μA	$V_{CC} = 5 \text{ V},$ $V_{IN} = 0 \text{ V}$	Reference value	
			—	35.0	—		$V_{CC} = 2.7 \text{ V},$ $V_{IN} = 0 \text{ V}$		

SSR31—Serial Status Register31

H'9C

SCI3

Bit	7	6	5	4	3	2	1	0
	TDRE31	RDRF31	OER31	FER31	PER31	TEND31	MPBR31	MPBT31
Initial value	1	0	0	0	0	1	0	0
Read/Write	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R	R	R/W

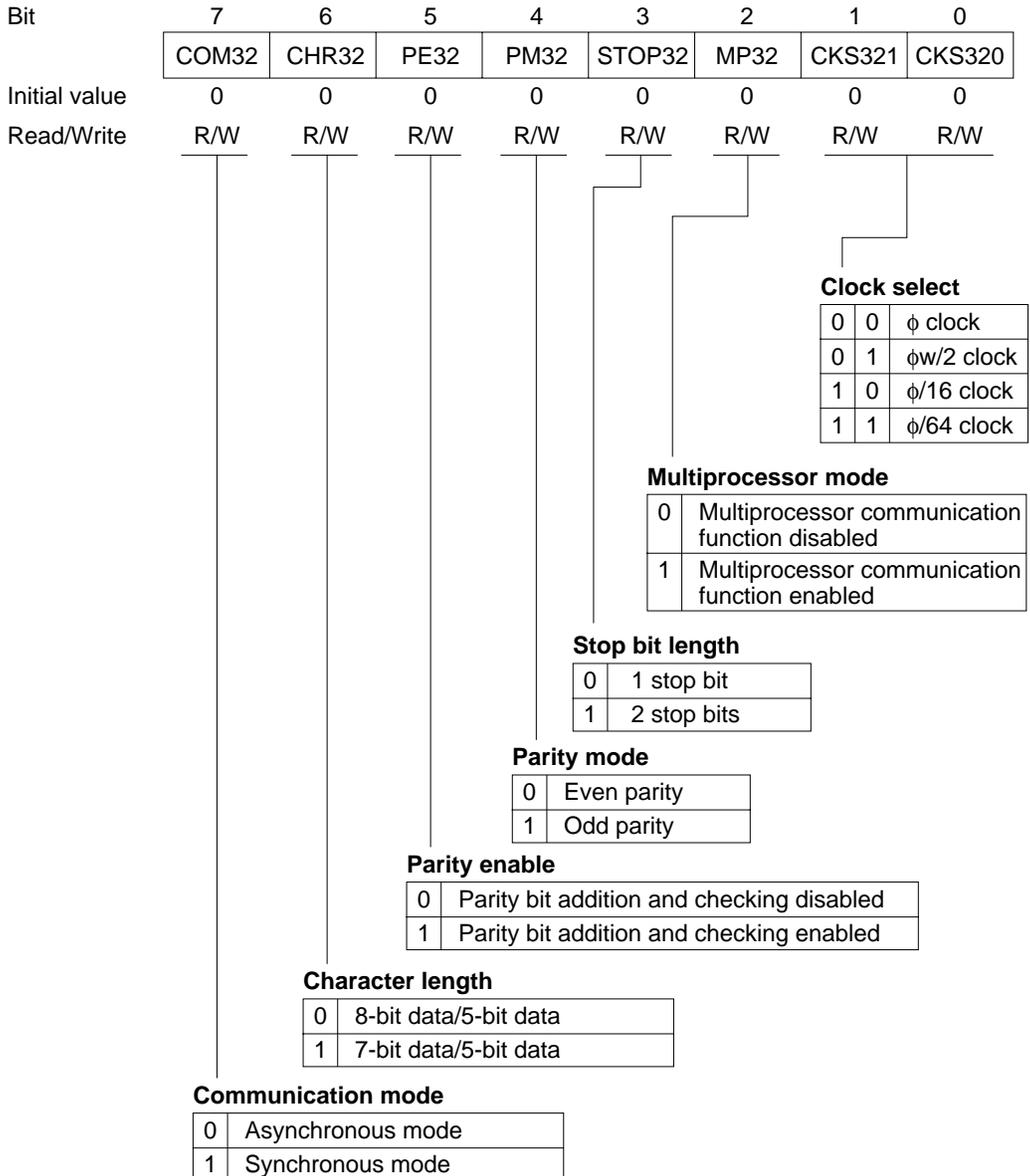


Note: * Only a write of 0 for flag clearing is possible.

SMR32—Serial Mode Register 32

H'A8

SCI32



C.5 Block Diagram of Port 6

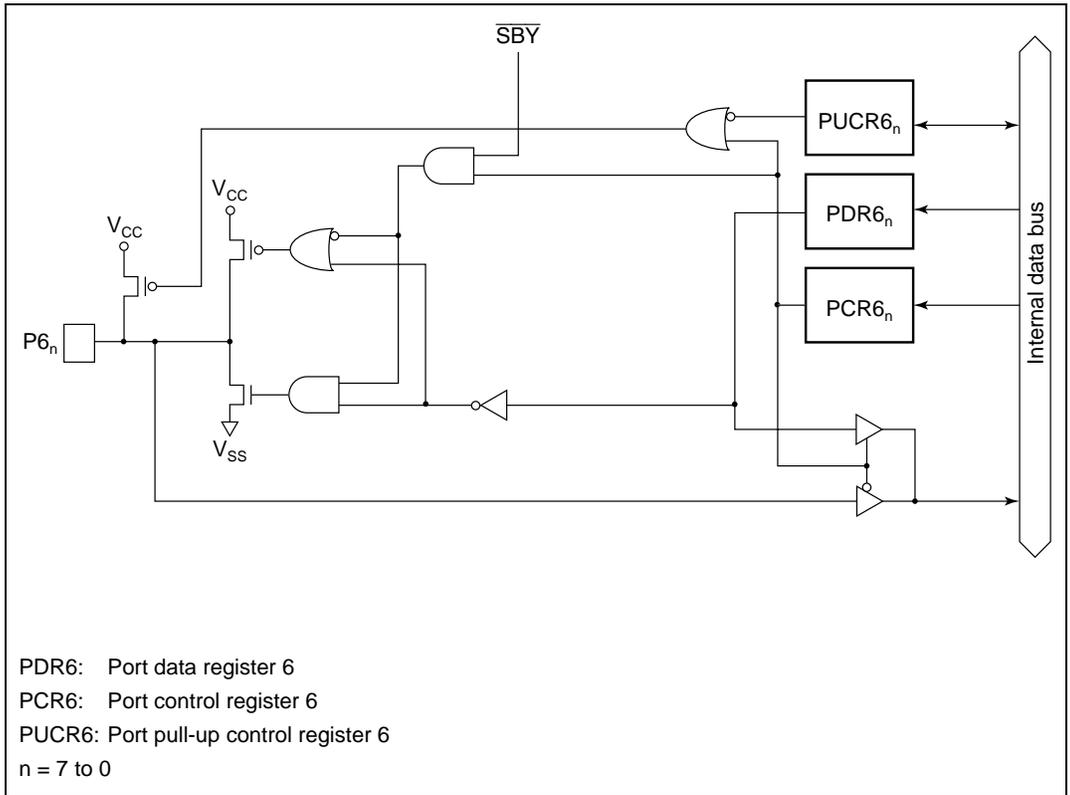


Figure C.5 Port 6 Block Diagram